TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

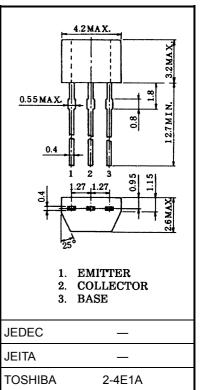
# 2SA1048

Audio Frequency Amplifier Applications

- Small package
- High voltage:  $V_{CEO} = -50 V (min)$
- High hFE:  $hFE = 70 \sim 400$
- Excellent hFE linearity: hFE (IC = -0.1 mA)/hFE (IC = -2 mA) = 0.95 (typ.)
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SC2458

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	Ι <sub>C</sub>	-150	mA
Base current	Ι <sub>Β</sub>	-50	mA
Collector power dissipation	P <sub>C</sub>	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



Weight: 0.13 g (typ.)

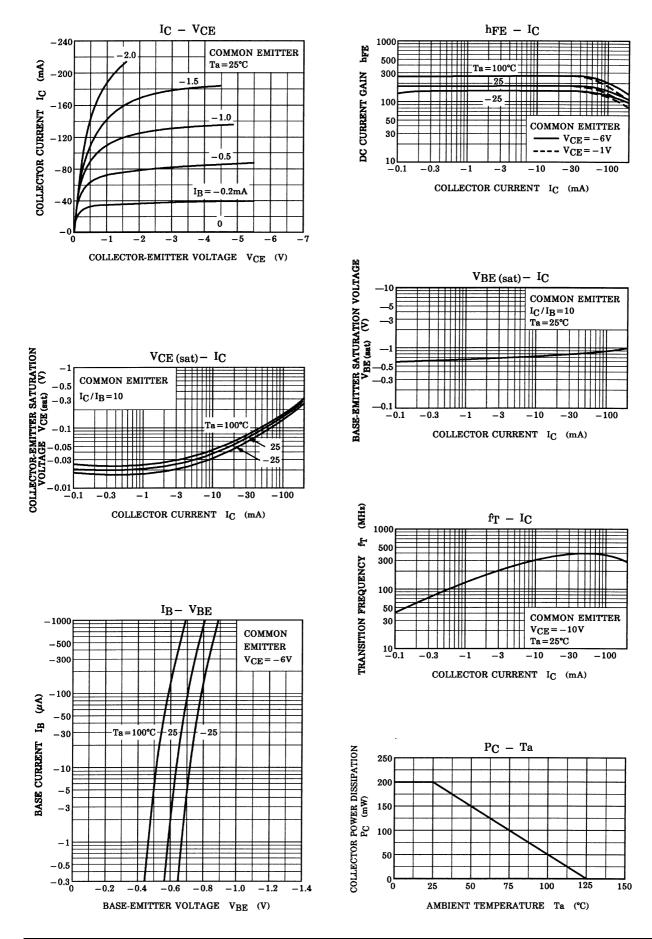
## **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, \text{ I}_{E} = 0$			-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, \text{ I}_{C} = 0$	_	_	-0.1	μA
DC current gain	h <sub>FE</sub> (Note)	$V_{CE} = -6 \text{ V}, \text{ I}_{C} = -2 \text{ mA}$	70	_	400	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_{C} = -100 \text{ mA}, I_{B} = -10 \text{ mA}$	_	-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, \text{ I}_{C} = -1 \text{ mA}$	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 V$ , $I_E = 0$ , $f = 1 MHz$	_	4	7	pF
Noise figure	NF	$V_{CE}$ = -6 V, $I_C$ = -0.1 mA, f = 1 kHz, $R_G$ = 10 $k\Omega$	_	1.0	10	dB

Note: hFE classification O: 70~140, Y: 120~240, GR: 200~400

Unit: mm

# **TOSHIBA**



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